NSN 5962-01-325-2170

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View Online at https://aerobasegroup.com/nsn/5962-01-325-2170

Body Length:

Between 0.342 inches and 0.358 inches

Body Width:

Between 0.342 inches and 0.358 inches

Body Height:

Between 0.060 inches and 0.100 inches

Maximum Power Dissipation Rating:

165.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Low power and schottky and 3-state output and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Design Function And Quantity:

8 gate, buffer

Case Outline Source And Designator:

C-2 mil-m-38510

Current Rating Per Characteristic:

17.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Special Features:

Nuclear hardness critical items

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

20 leadless

Specification Data:

81349-mil-m-38510/383 government specification

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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